IMPORTANT NOTICE

10 December 2015

1. Global joint venture starts operations as WeEn Semiconductors

Dear customer,

As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

In this document where the previous NXP references remain, please use the new links as shown below.

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Thank you for your cooperation and understanding,

WeEn Semiconductors

DATA SHEET

BUJ105AB
Silicon Diffused Power Transistor

Product specification

October 2001

Silicon Diffused Power Transistor BUJ105AB

GENERAL DESCRIPTION

High-voltage, high-speed planar-passivated npn power switching transistor in SOT404 (D^2-PAK) surface-mount package intended for use in high frequency electronic lighting ballast applications, converters, inverters, switching regulators, motor control systems, etc.

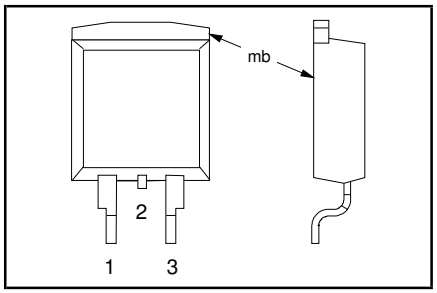
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V_{CESM}	Collector-emitter voltage peak value	V_{BE} = 0 V	-	700	V
V_{CBO}	Collector-Base voltage (open emitter)		-	700	V
V_{CEO}	Collector-emitter voltage (open base)		-	400	V
I_C	Collector current (DC)		-	8	A
I_{CM}	Collector current peak value		-	16	A
P_{tot}	Total power dissipation	$T_{mb} \leq 25$ ˚C	-	125	W
V_{CEsat}	Collector-emitter saturation voltage	I_C = 4.0 A;I_B = 0.8 A	0.3	1.0	V
h_{FEsat}		I_C = 4.0 A; V_{CE} = 5 V	11	15	
t_f	Fall time	I_C = 5 A; I_{B1} = 1 A	20	50	ns

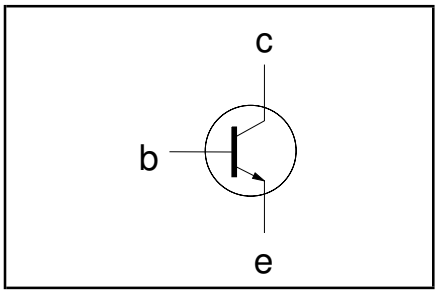
PINNING - SOT404

PIN	DESCRIPTION
1	base
2	collector
3	emitter
mb	collector

PIN CONFIGURATION



SYMBOL



LIMITING VALUES8

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CESM}	Collector to emitter voltage	V_{BE} = 0 V	-	700	V
V_{CEO}	Collector to emitter voltage (open base)		-	400	V
V_{CBO}	Collector to base voltage (open emitter)		-	700	V
I_C	Collector current (DC)		-	8	A
I_{CM}	Collector current peak value		-	16	A
I_B	Base current (DC)		-	4	A
I_{BM}	Base current peak value		-	8	A
P_{tot}	Total power dissipation	$T_{mb} \leq 25$ ˚C	-	125	W
T_{stg}	Storage temperature		-65	150	˚C
T_j	Junction temperature		-	150	˚C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
$R_{th\ j\text{-}mb}$	Thermal resistance junction to mounting base		-	1.0	K/W
$R_{th\ j\text{-}a}$	Thermal resistance junction to ambient	minimum footprint, FR4 board	55	-	K/W

STATIC CHARACTERISTICS

T_{mb} = 25 ˚C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I_{CES},I_{CBO}	Collector cut-off current [1]	V_{BE} = 0 V; V_{CE} = $V_{CESMmax}$	-	-	0.2	mA
I_{CES}		V_{BE} = 0 V; V_{CE} = $V_{CESMmax}$; T_j = 125 ˚C	-	-	0.5	mA
I_{CEO}	Collector cut-off current	V_{CEO} = $V_{CEOMmax}$ (400V)	-	-	0.1	mA
I_{EBO}	Emitter cut-off current	V_{EB} = 9 V; I_C = 0 A	-	-	1	mA
$V_{CEOsust}$	Collector-emitter sustaining voltage	I_B = 0 A; I_C = 10 mA; L = 25 mH	400	-	-	V
V_{CEsat}	Collector-emitter saturation voltage	I_C = 4.0 A;I_B = 0.8 A	-	0.3	1.0	V
V_{BEsat}	Base-emitter saturation voltage	I_C = 4.0 A;I_B = 0.8 A	-	1.0	1.5	V
h_{FE}	DC current gain	I_C = 1 mA; V_{CE} = 5 V	10	14	34	
h_{FE}		I_C = 500 mA; V_{CE} = 5 V	13	23	36	
h_{FEsat}		I_C = 4.0 A; V_{CE} = 5 V	8	11	15	

DYNAMIC CHARACTERISTICS

T_{mb} = 25 ˚C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
	Switching times (resistive load)	I_{Con} = 5 A; I_{Bon} = -I_{Boff} = 1 A; R_L = 75 ohms; V_{BB2} = 4 V;			
t_{on}	Turn-on time		0.65	1	µs
t_s	Turn-off storage time		1.8	2.5	µs
t_f	Turn-off fall time		0.3	0.5	µs
	Switching times (inductive load)	I_{Con} = 5 A; I_{Bon} = 1 A; L_B = 1 µH; -V_{BB} = 5 V			
t_s	Turn-off storage time		1.2	1.7	µs
t_f	Turn-off fall time		20	50	ns
	Switching times (inductive load)	I_{Con} = 5 A; I_{Bon} = 1 A; L_B = 1 µH; -V_{BB} = 5 V; T_j = 100 ˚C			
t_s	Turn-off storage time		1.4	1.9	µs
t_f	Turn-off fall time		25	100	ns

1 Measured with half sine-wave voltage (curve tracer).

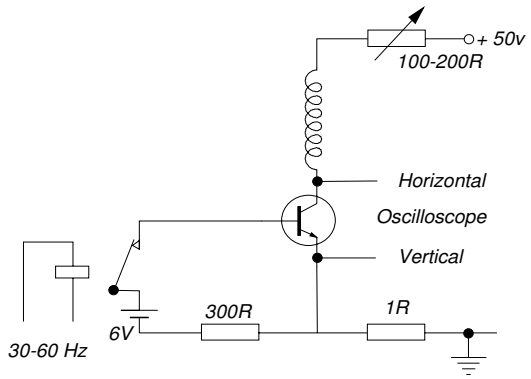


Fig.1. Test circuit for $V_{CEOsust}$.

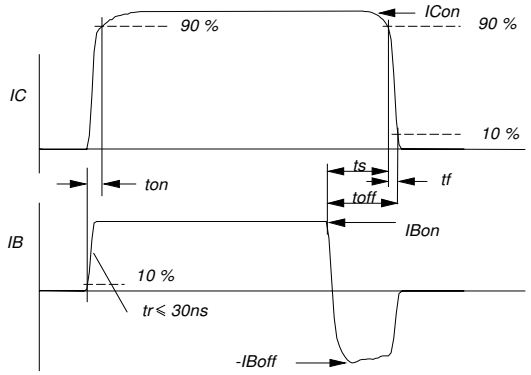


Fig.4. Switching times waveforms with resistive load.

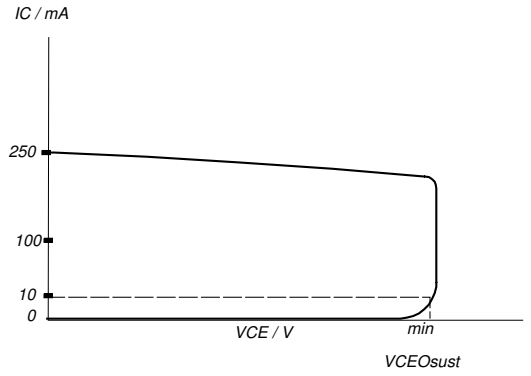


Fig.2. Oscilloscope display for $V_{CEOsust}$.

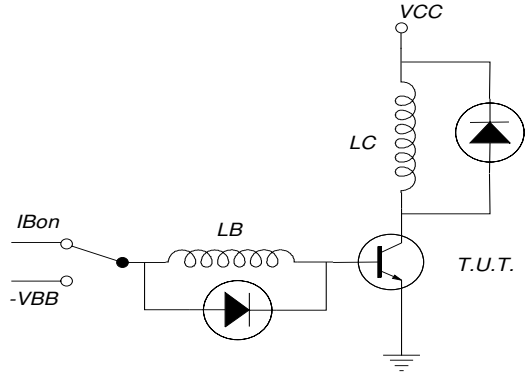


Fig.5. Test circuit inductive load.
V_{CC} = 300 V; $-V_{BE}$ = 5 V; L_C = 200 uH; L_B = 1 uH

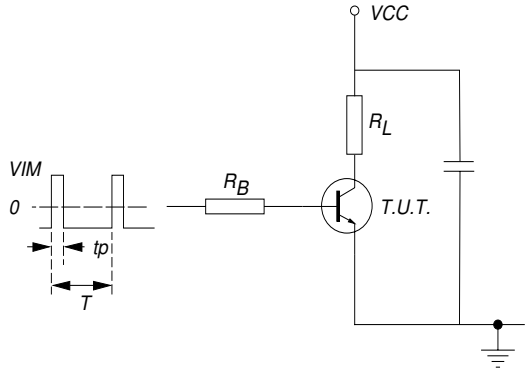


Fig.3. Test circuit resistive load. V_{IM} = -6 to +8 V
V_{CC} = 250 V; t_p = 20 μs; δ = t_p / T = 0.01.
R_B and R_L calculated from I_{Con} and I_{Bon} requirements.

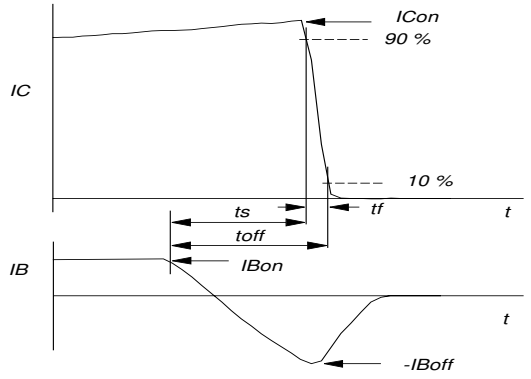


Fig.6. Switching times waveforms with inductive load.

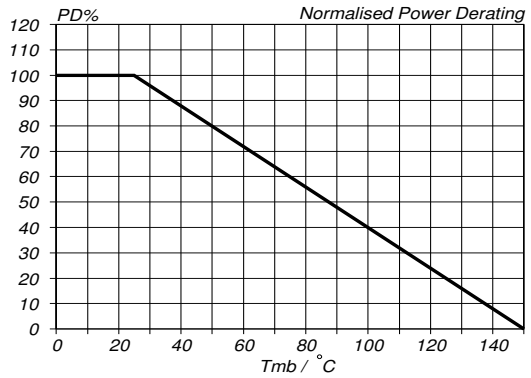


Fig.7. Normalised power dissipation. PD% = 100·PD/PD $_{25°C}$ = f (T_{mb})

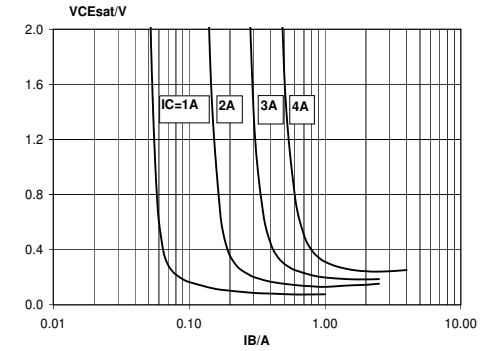


Fig.10. Collector-Emitter saturation voltage. Solid lines = typ values, V_{CEsat} = f(IB); T_j=25˚C.

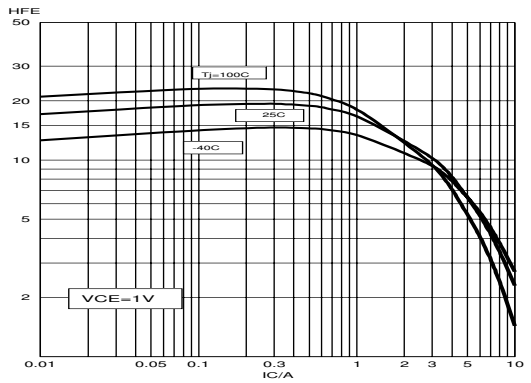


Fig.8. Typical DC current gain. h_{FE} = f(I_C) parameter V_{CE}

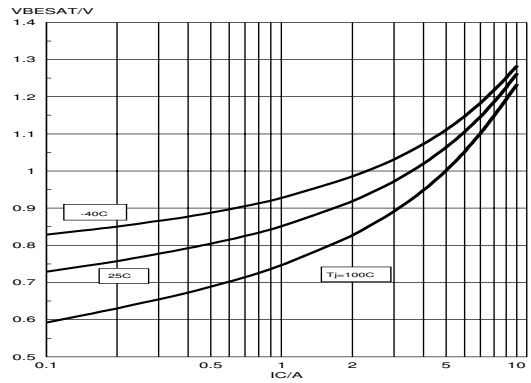


Fig.11. Base-Emitter saturation voltage. Solid lines = typ values, V_{BEsat} = f(IC); at IC/IB =4.

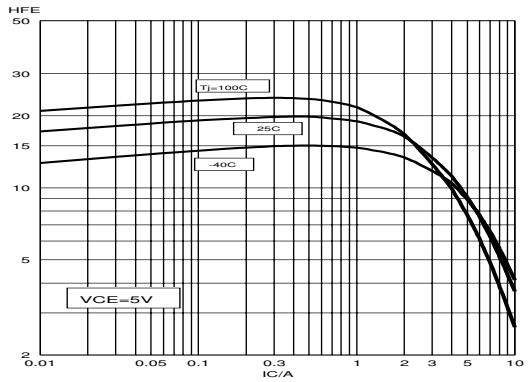


Fig.9. Typical DC current gain. h_{FE} = f(I_C) parameter V_{CE}

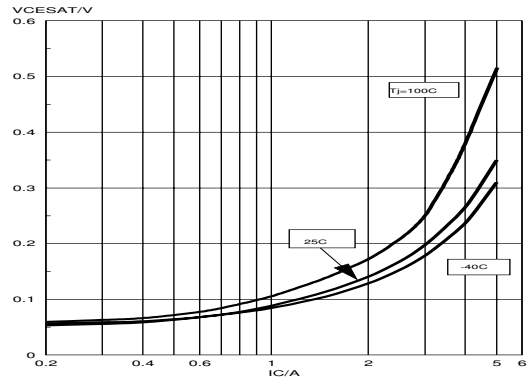


Fig.12. Collector-Emitter saturation voltage. Solid lines = typ values, V_{CEsat} = f(IC); at IC/IB =4.

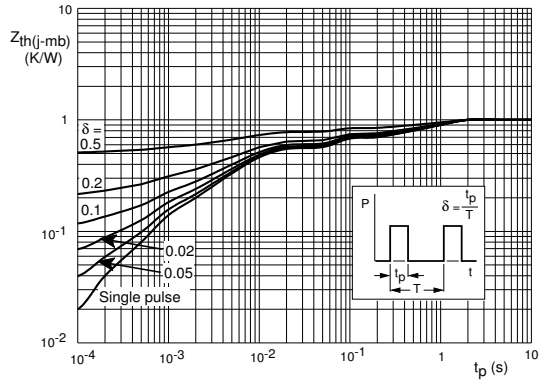


Fig.13. Transient thermal impedance. $Z_{th\ j\text{-}mb} = f(t)$; parameter $\delta = t_p/T$

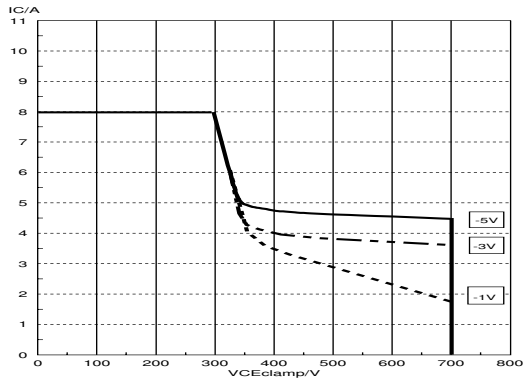


Fig.15. Reverse bias safe operating area ($T_j < T_{jmax}$) for $-V_{BE}$ = 5V,3V & 1V.

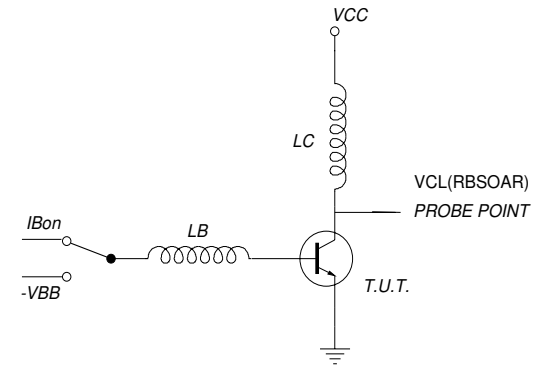


Fig.14. Test circuit for reverse bias safe operating area.

V_{clamp} < 700V; V_{cc} = 150V; $-V_{be}$ = 5V,3V & 1V; L_B = 1μH; L_C = 200μH.

MECHANICAL DATA

Dimensions in mm

Net Mass: 1.4 g

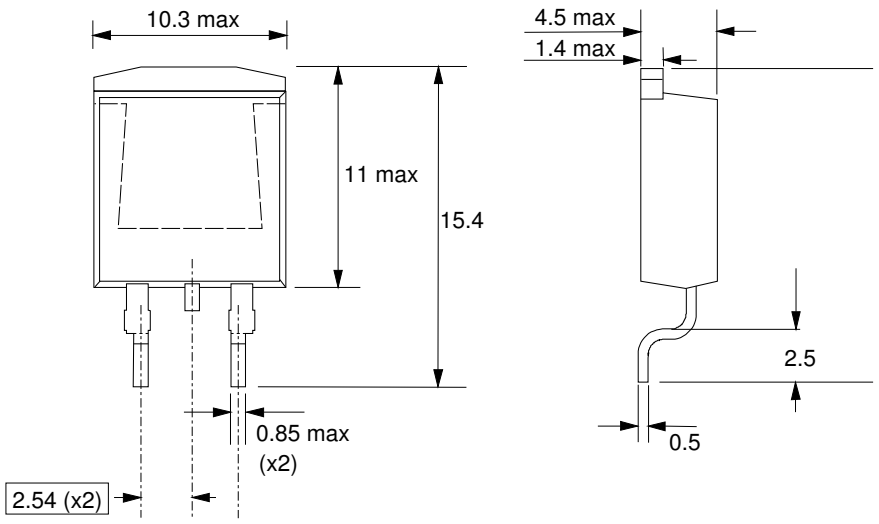


Fig.16. SOT404 : centre pin connected to mounting base.

MOUNTING INSTRUCTIONS

Dimensions in mm

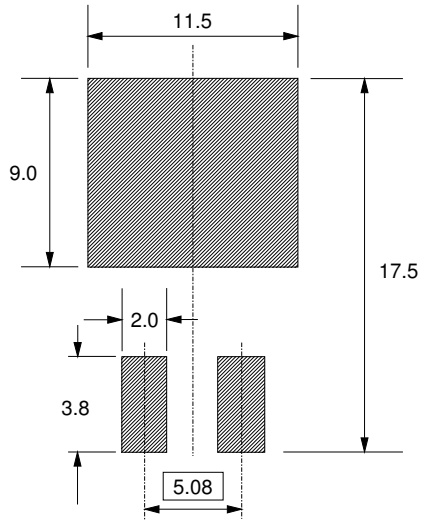


Fig.17. SOT404 : soldering pattern for surface mounting.

Notes

1. Plastic meets UL94 V0 at 1/8".

Legal information

DATA SHEET STATUS

DOCUMENT STATUS[1]	PRODUCT STATUS[2]	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Customer notification

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